



1.Anode 2.Cathode 3. Anode



## Features:

- 1) Low power loss, high efficiency, High surge capacity.
- 2) For use in low voltage, high frequency inverters, Free wheeling, and polarity protection applications.
- 3) Metal silicon junction. Majority carrier conduction.
- 4) High current Capability, low forward voltage drop.
- 5) Guard ring for over voltage protection.

**Absolute Maximum Ratings:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Value	Unit
<b>Maximum Recurrent Peak Reverse Voltage</b>	<b>V<sub>RRM</sub></b>	200	V
<b>Maximum Average</b>	<b>I<sub>F(AV)</sub></b>	10	A
<b>Maximum RMS Voltage</b>	<b>V<sub>RMS</sub></b>	140	V
<b>Maximum DC Blocking Voltage</b>	<b>V<sub>R(DC)</sub></b>	200	V
<b>Maximum Average Forward Current</b>	<b>I<sub>F(AV)</sub></b>	10	A
<b>Peak Forward Surge Current: 8.3ms single half sine wave superimposed on rated load (JEDEC method)</b>	<b>I<sub>FSM</sub></b>	200	A
<b>Forward Voltage</b>	<b>V<sub>F</sub></b>	0.92	V
<b>Maximum DC Reverse Current at Rated DC Blocking Voltage</b>	$T_j=25^\circ\text{C}$	0.1	mA
	$T_j=125^\circ\text{C}$	20	mA
<b>Maximum Operating Junction Temperature</b>	<b>T<sub>J</sub></b>	150	°C
<b>Storage Temperature</b>	<b>T<sub>stg</sub></b>	-50 TO+175	°C